

Silicon PIN Photodiode

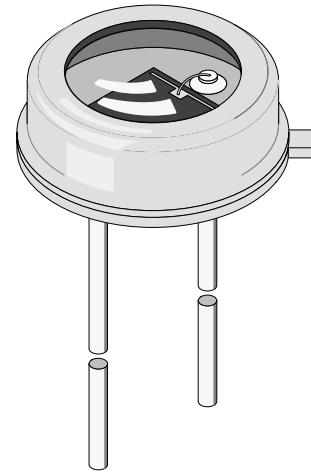
Description

S153P is a high speed and high sensitive PIN photodiode in a hermetically sealed short TO-5 package.

Due to its flat, waterclear glass window the device is sensitive to visible and near infrared radiation. The large active area combined with a flat case gives a high sensitivity at a wide viewing angle.

Features

- High photo sensitivity
- Large radiant sensitive area $A=7.5 \text{ mm}^2$
- Fast response times
- Small junction capacitance
- For photodiode and photovoltaic operation
- Hermetically sealed case
- Wide angle of half sensitivity $\varphi = \pm 55^\circ$
- Suitable for visible and near infrared radiation
- Suitable to couple with glass fiber



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Applications

Applications requiring high speed and high sensitive PIN photodiodes in hermetically sealed packages.

Absolute Maximum Ratings

 $T_{amb} = 25^{\circ}\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Reverse Voltage		V_R	50	V
Power Dissipation	$T_{amb} \leq 50^{\circ}\text{C}$	P_V	300	mW
Junction Temperature		T_j	125	$^{\circ}\text{C}$
Operating Temperature Range		T_{amb}	-55...+125	$^{\circ}\text{C}$
Soldering Temperature	$t \leq 5\text{ s}$	T_{sd}	260	$^{\circ}\text{C}$
Thermal Resistance Junction/Ambient		R_{thJA}	250	K/W

Basic Characteristics

 $T_{amb} = 25^{\circ}\text{C}$

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Breakdown Voltage	$I_R = 100\ \mu\text{A}, E = 0$	$V_{(BR)}$	50			V
Reverse Dark Current	$V_R = 10\ \text{V}, E = 0$	I_{ro}		2	30	nA
Diode Capacitance	$V_R = 0\ \text{V}, f = 1\ \text{MHz}, E = 0$	C_D		75		pF
Diode Capacitance	$V_R = 3\ \text{V}, f = 1\ \text{MHz}, E = 0$	C_D		25	40	pF
Open Circuit Voltage	$E_A = 1\ \text{klx}$	V_o		350		mV
Temp. Coefficient of V_o	$E_A = 1\ \text{klx}$	TK_{V_o}		-2.6		mV/K
Short Circuit Current	$E_A = 1\ \text{klx}$	I_k		80		μA
Short Circuit Current	$E_e = 1\ \text{mW}/\text{cm}^2, \lambda = 950\ \text{nm}$	I_k		47		μA
Temp. Coefficient of I_k	$E_A = 1\ \text{klx}$	TK_{I_k}		0.18		%/K
Reverse Light Current	$E_A = 1\ \text{klx}, V_R = 5\ \text{V}$	I_{ra}		85		μA
Reverse Light Current	$E_e = 1\ \text{mW}/\text{cm}^2, \lambda = 950\ \text{nm}, V_R = 5\ \text{V}$	I_{ra}	40	50		μA
Absolute Spectral Sensitivity	$V_R = 5\ \text{V}, \lambda = 900\ \text{nm}$	$s(\lambda)$		0.6		A/W
Angle of Half Sensitivity		ϕ		± 55		deg
Wavelength of Peak Sensitivity		λ_p		900		nm
Range of Spectral Bandwidth		$\lambda_{0.5}$		600...1050		nm
Noise Equivalent Power	$V_R = 10\ \text{V}, \lambda = 950\ \text{nm}$	NEP		4.2×10^{-14}		$\text{W}/\sqrt{\text{Hz}}$
Rise Time	$V_R = 10\ \text{V}, R_L = 1\ \text{k}\Omega, \lambda = 820\ \text{nm}$	t_r		100		ns
Fall Time	$V_R = 10\ \text{V}, R_L = 1\ \text{k}\Omega, \lambda = 820\ \text{nm}$	t_f		100		ns

Typical Characteristics ($T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified)

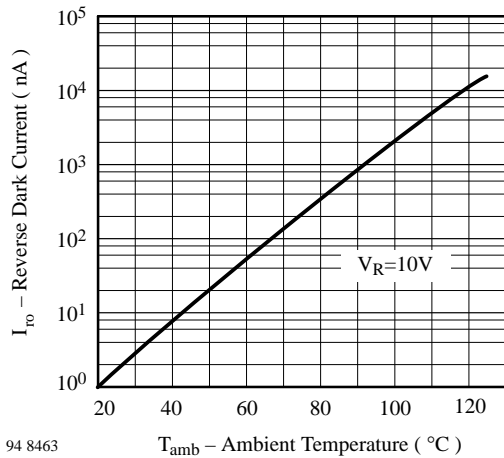


Figure 1 : Reverse Dark Current vs. Ambient Temperature

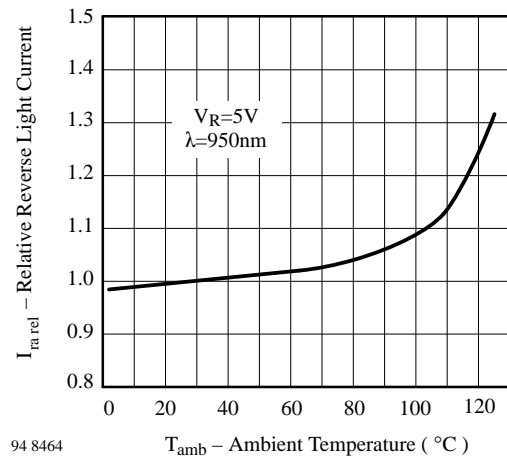


Figure 2 : Relative Reverse Light Current vs. Ambient Temperature

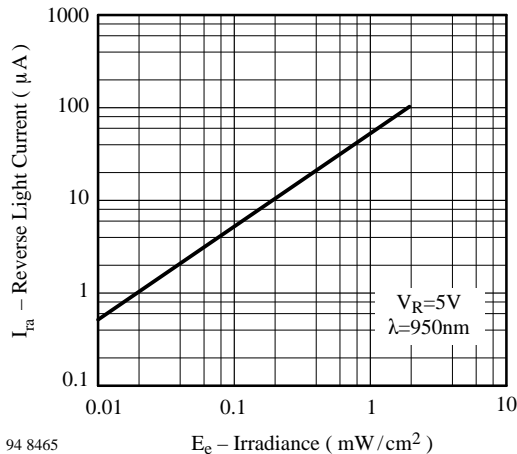


Figure 3 : Reverse Light Current vs. Irradiance

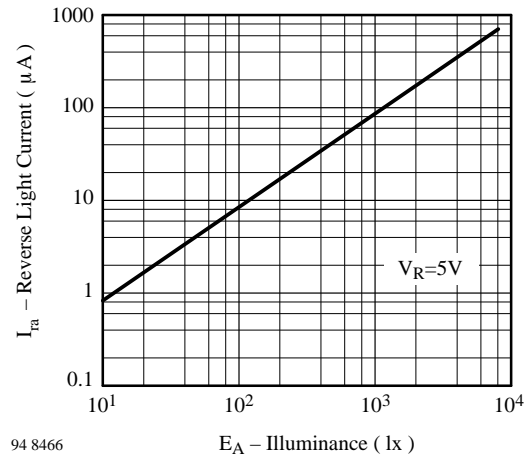


Figure 4 : Reverse Light Current vs. Illuminance

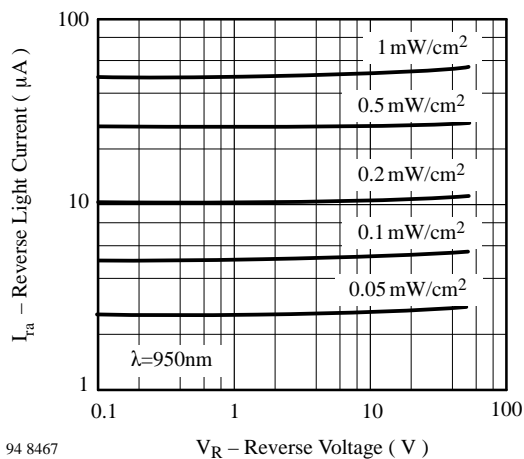


Figure 5 : Reverse Light Current vs. Reverse Voltage

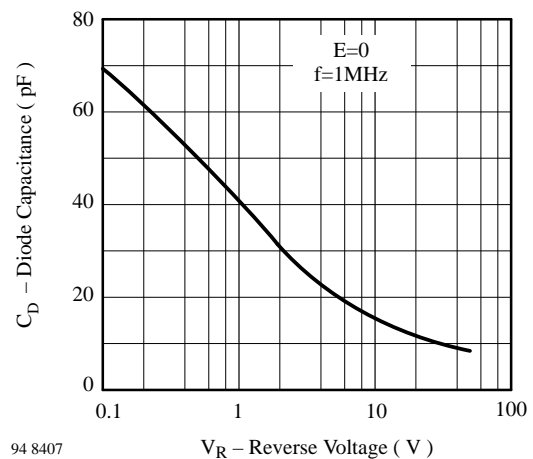


Figure 6 : Diode Capacitance vs. Reverse Voltage

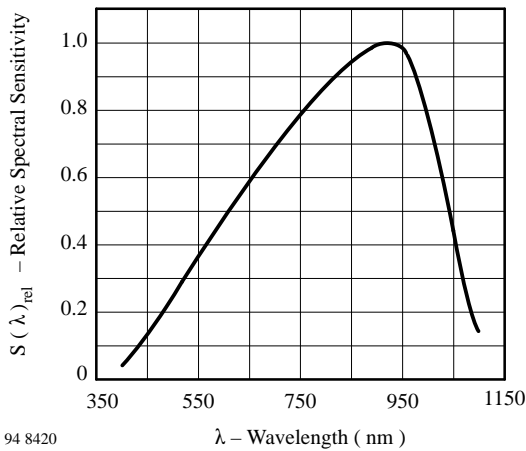


Figure 7 : Relative Spectral Sensitivity vs. Wavelength

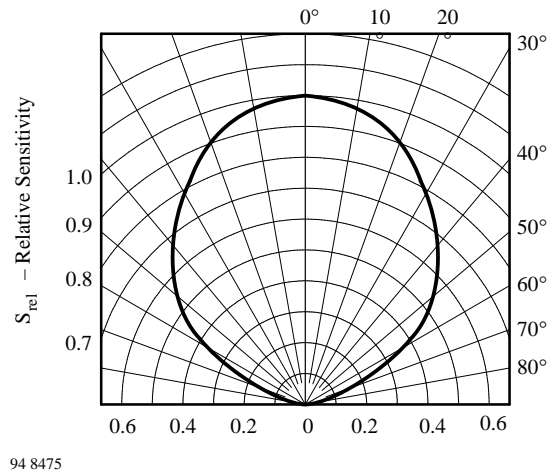
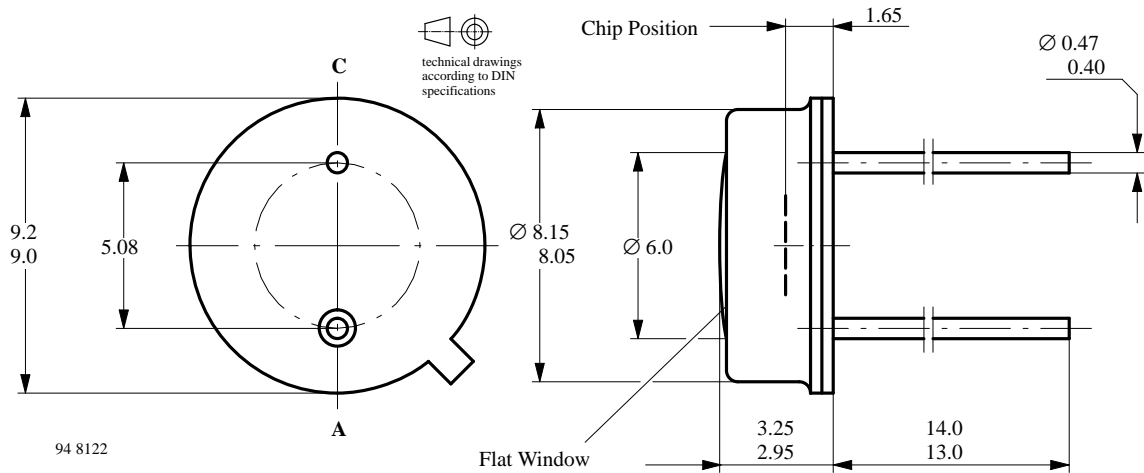


Figure 8 : Relative Radiant Sensitivity vs. Angular Displacement

Dimensions in mm



We reserve the right to make changes to improve technical design without further notice.

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